
Features

- APD with 0.04 mm² active area
- 230 μm diameter active area
- High gain at low bias voltage
- Fast rise time, low capacitance
- Optimum gain: 50-60

Description

Circular active area APD chip with 230 μm diameter. PCB-based non hermetic SMD package with clear resin potting. Reflow solderable.

Application

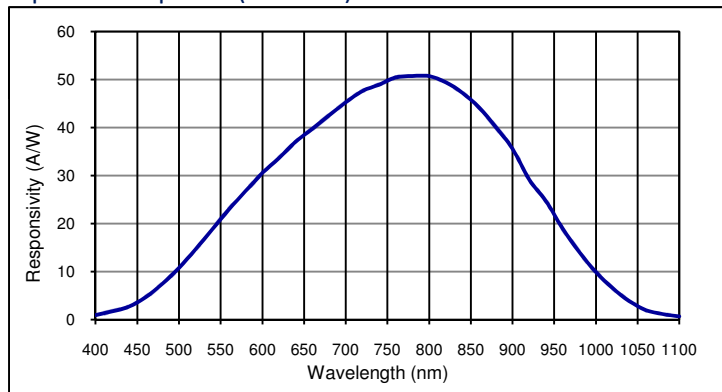
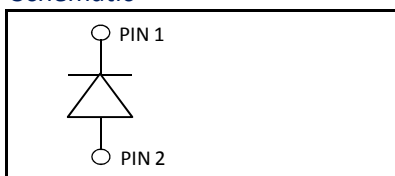
- Laser range finder
- High speed photometry
- High speed optical communications
- Medical equipment

RoHS

2002/95/EC


Absolute maximum ratings

| Symbol | Parameter | Min | Max | Unit |
|-------------------|-------------------------------|-----|------|------|
| T _{STG} | Storage temp | -40 | 100 | °C |
| T _{OP} | Operating temp | -20 | 70 | °C |
| M _{max} | Gain (I _{PO} = 1 nA) | 200 | | |
| I _{PEAK} | Peak DC current | | 0.25 | mA |

Spectral response (M = 100)

Schematic

Electro-optical characteristics @ 23°C

| Symbol | Characteristic | Test Condition | Min | Typ | Max | Unit |
|-----------------|-------------------------|---|--------------|------|-----|-----------------|
| | Active area | | diameter 230 | | | μm |
| | Active area | | 0.04 | | | mm ² |
| I _D | Dark current | M = 100 | | 0.3 | 1.0 | nA |
| C | Capacitance | M = 100 | | 1.2 | | pF |
| | Responsivity | M = 100; λ = 800 nm | 45 | 50 | | A/W |
| t _R | Rise time | M = 100; λ = 905 nm; R _L = 50 Ω | | 0.18 | | ns |
| | Cut-off frequency | -3dB | | 2 | | GHz |
| V _{BR} | Breakdown voltage | I _R = 2 μA, V _{BR} - binning available* | 80 | | 160 | V |
| | Temperature coefficient | Change of V _{BR} with temperature | | 0.45 | | V/K |
| | Excess noise factor | M = 100 | | 2.2 | | |
| | Excess noise index | M = 100 | | 0.2 | | |

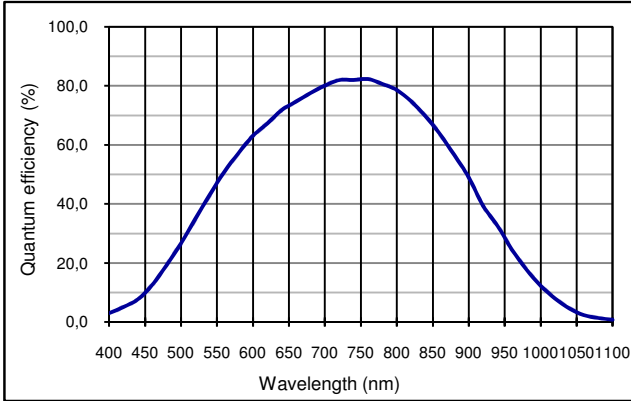
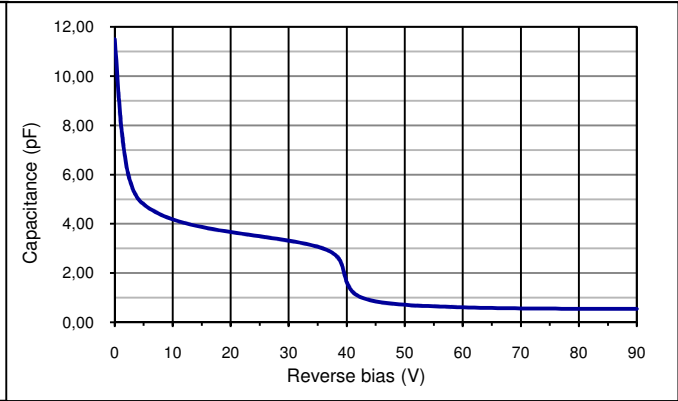
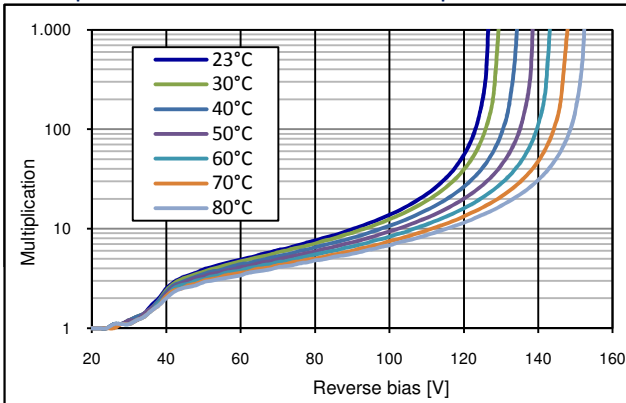
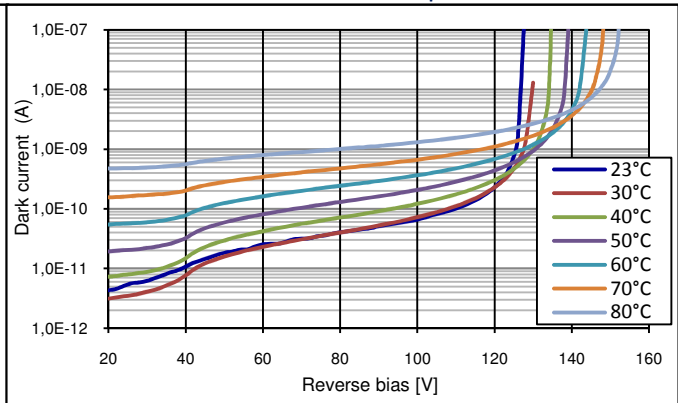
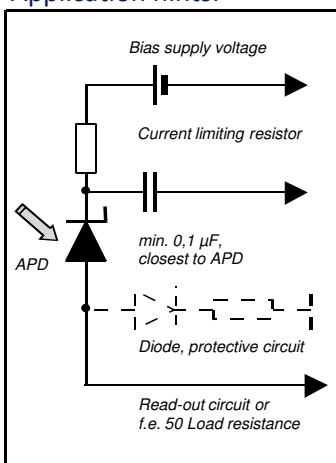
*please add a "01" to the order number for VBR-class 80V-120V and a "02" for VBR-class 120V-160V

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Quantum efficiency (23 °C)

Capacitance as fct of reverse bias (23 °C)

Multiplication as fct of bias and temperature

Dark current as fct of bias and temperature

Application hints:


- Current should be limited by a protecting resistor or current limiting - IC inside the power supply
- For low light level applications blocking of ambient light should be used
- For high gain applications bias voltage should be temperature compensated
- Please consider basic ESD protection while handling
- Use low noise read-out - IC
- For further questions please refer to document "Instructions for handling and processing"
- Optimum gain: 50-60

Package dimension

tbd; large quantities on reel, small quantities in tray

Disclaimer: Due to our strive for continuous improvement, specifications are subject to change within our PCN policy according to JESD46C.

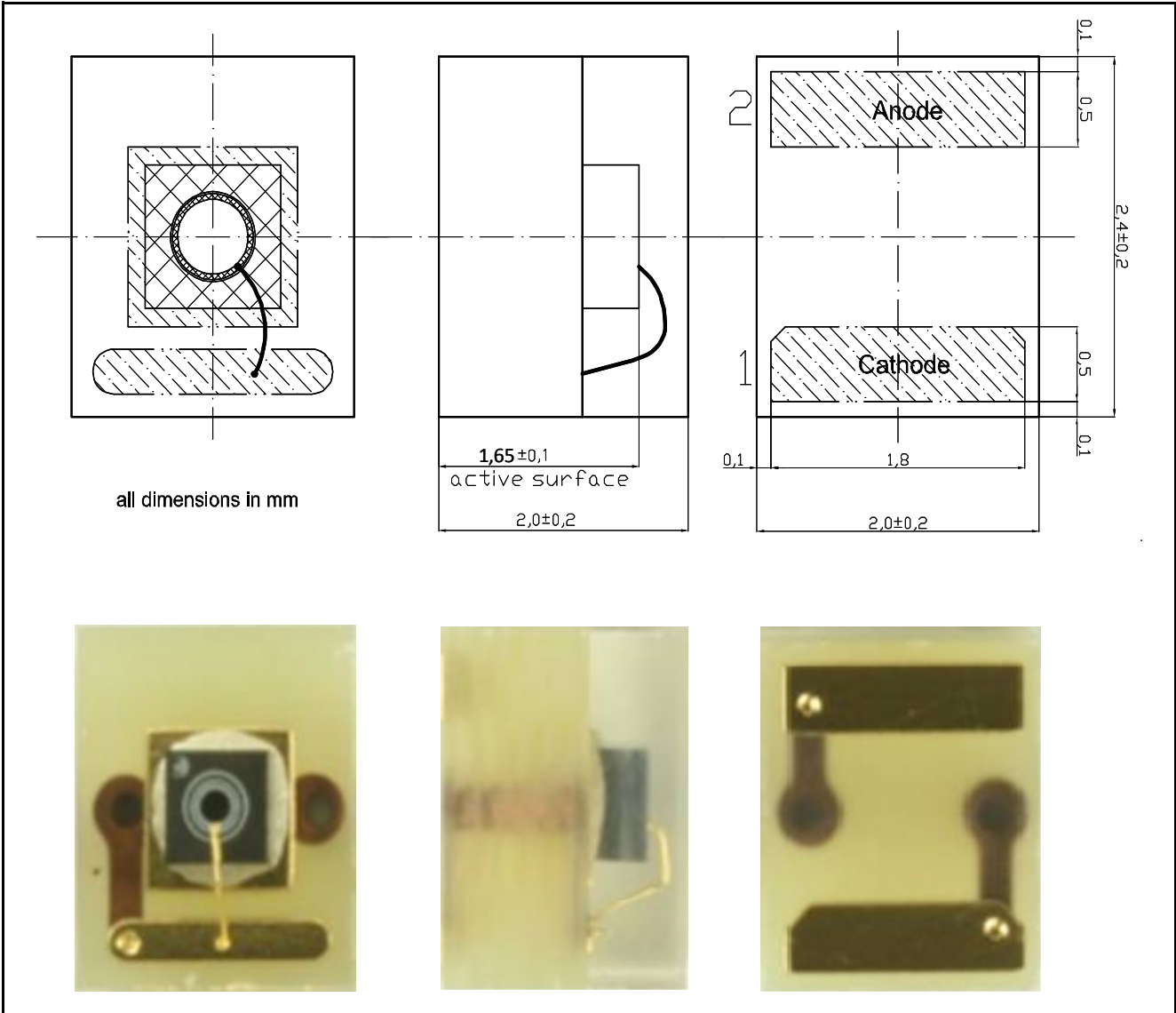
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Technical drawing



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